NSN 5962-00-470-2574

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Body Length:	
1.220 inches	
Body Width:	
0.530 inches	
Body Height:	
0.200 inches	
Maximum Power Dissipation Rating:	
1.25 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Monolithic and hermetically sealed and negative outputs and positive outputs	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
P-type metal oxide-semiconductor logic	
Input Circuit Pattern:	
4 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-30.0 volts power source and 0.5 volts power source	
Time Rating Per Chacteristic:	
100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to lo	ow level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
12464-b77t0197 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer draw	ving, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measures	

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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